



Fast-Transient Low-Dropout Regulator

Main Points



Introduction

Design specs

Design methodology

Simulation results

FOM and specs achieved

Design challenges

Introduction



- Who are we?
- Our goals
 Robust power management unit
- What is an LDO?
 Is it really an LDO?

Design Specs



Parameter	Name	Min	Тур	Max	Units	Comments
Power Supply Voltage	Vin	2.4		3.5	٧	
Output Voltage	Vout	0.85	1	1.25	٧	Large drop out
Untrimmed Output Voltage Accuracy			±6		%	
Load Current	lout	0.1		150	mA	Large range of current
Vin Ramp Rate	dVin/dt			0.2	mV/μs	
Rate of lout Change	dlout/dt			5	mA/ns	
Undershoot/Overshoot				50	mV	
Load Capacitance	CL			1	nF	Not large enough
Power Supply Rejection at 1 MHz	PSR1MHz	30			dB	
Power Supply Rejection at 10 MHz	PSR10MHz	20			dB	Large PSR bandwidth
Line Regulation			2		mV/V	
Load Regulation			50		mV/A	

Design Methodology

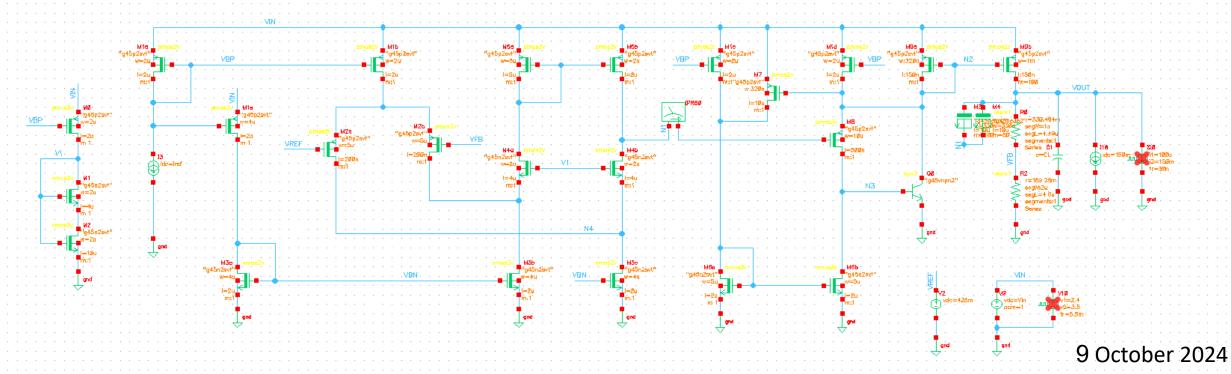


LDO Topology

We want a stable fast-transient topology

Error Amplifier's Topology

How is the input and output's swings?



Design Methodology



• Static gain error

Map it into V_{ref} , β and $A_{v_{error\ amplifier}}$

Stability constraints

Hard to achieve. What about Miller compensation?

Load and Line regulation

How to make the current percent change negligible?

Achieving PSR proposals

Simulation Results



1. DC operating parameters simulation

2. Transient load simulation

3. Transient input simulation

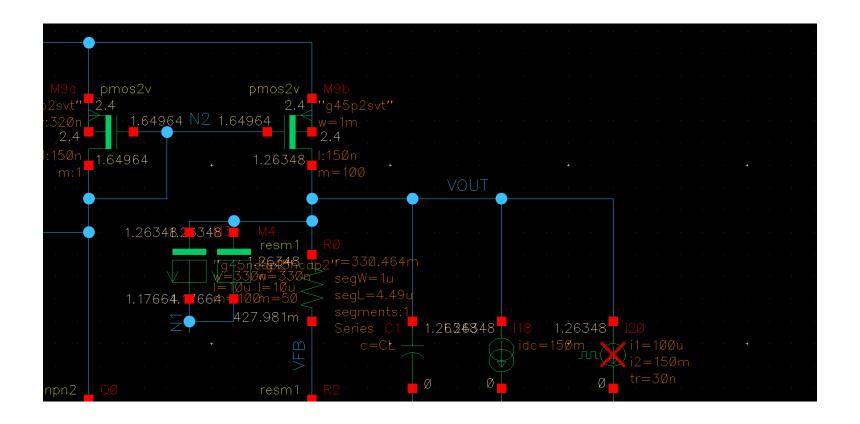
4. Stability analysis and PSR

DC OP Simulation



1. Max output error

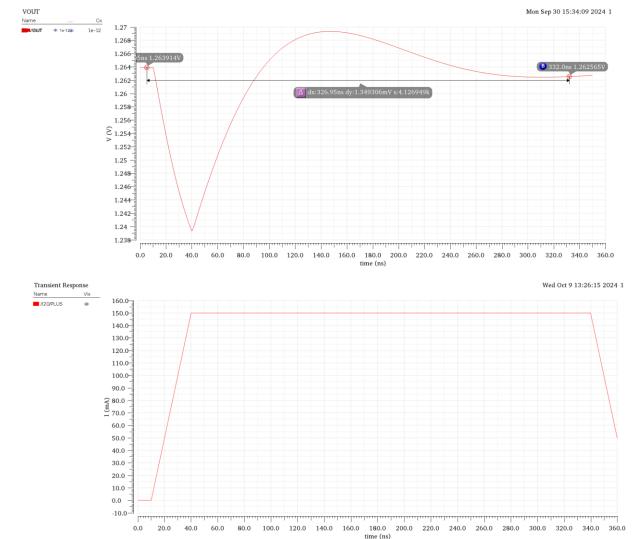
Evaluated at Minimum $loop\ gain$ (minimum V_{in} &minimum β)



Transient Load Simulation



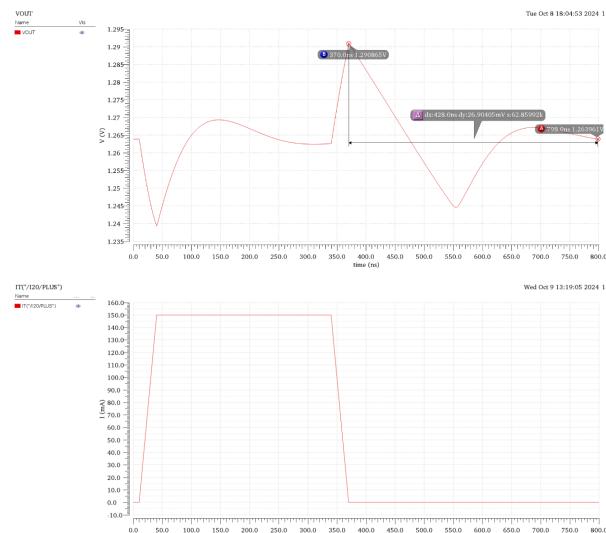
1. Load regulation



Transient Load Simulation



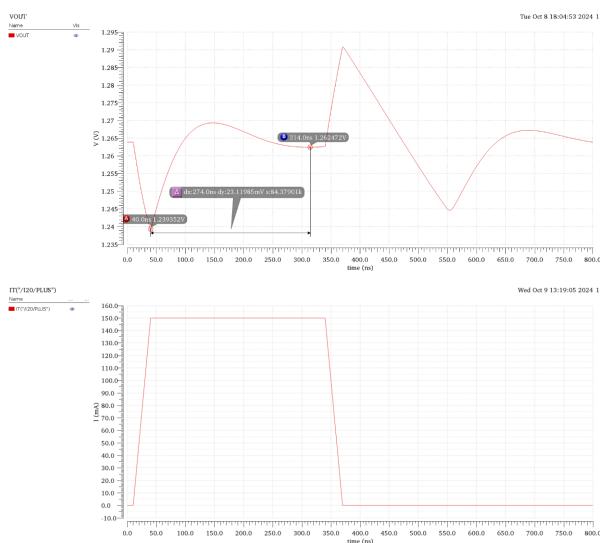
- 1. Load regulation
- 2. Overshoot



Transient Load Simulation



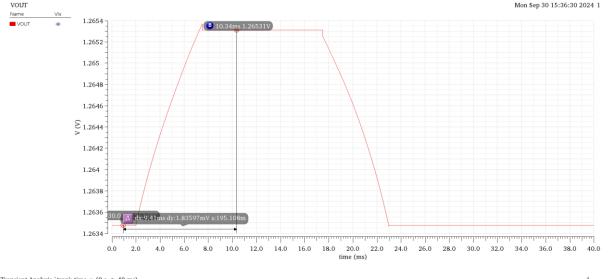
- 1. Load regulation
- 2. Overshoot
- 3. Undershoot

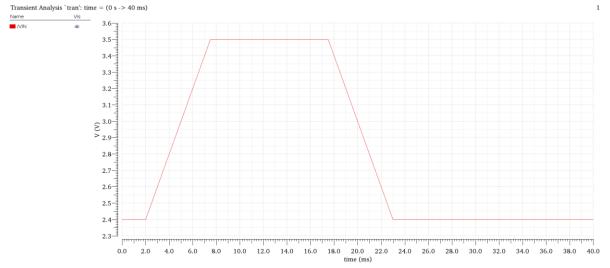


Transient Input Simulation



1. Line regulation

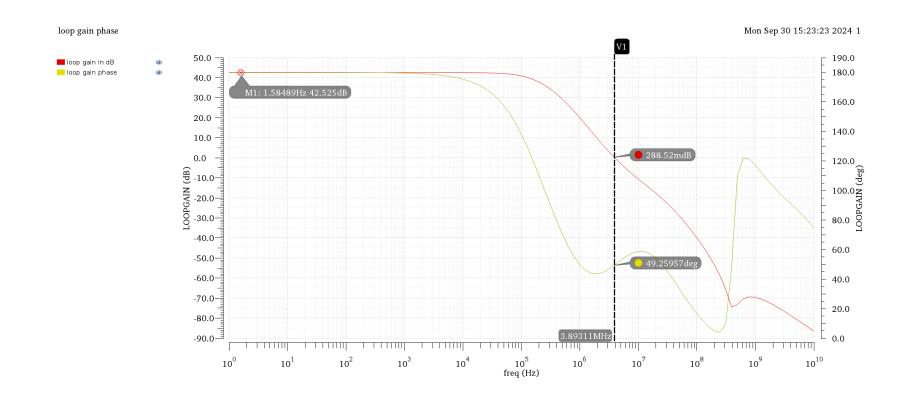




Stability Analysis and PSR



1. Phase Margin



Stability Analysis and PSR



1. Phase Margin

2. PSR

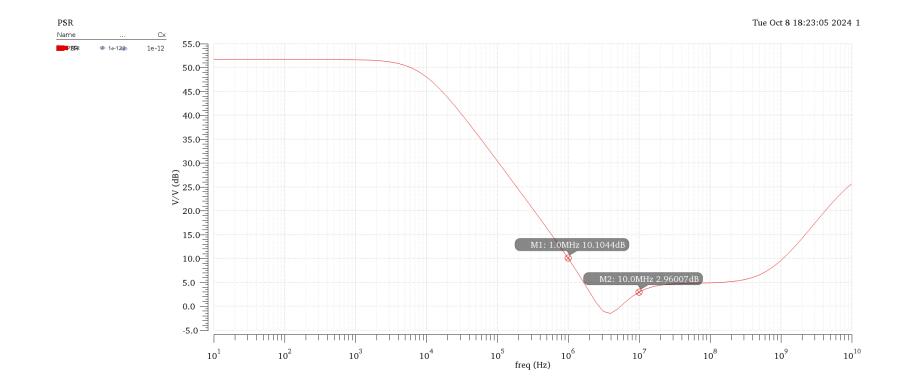


Figure of Merit



$$FOM = \frac{C_L * \Delta V_{out} * I_Q}{I_{L,max}^2} = 2.16 * 10^{-6} (ns)$$

Achieved Specs



Spec	Required	Achieved		
Technology used	45nm CMOS			
Supply Voltage	$2.4~V \rightarrow 3.5~V$	_		
Output Voltage	$0.85 V \rightarrow 1.25 V$	-		
Untrimmed output voltage accuracy	< ±6%	1%		
Load Current	$0.1 \ mA \rightarrow 150 \ mA$	-		
Undershoot/Overshoot	< 50 mV	27 mV		
Phase margin	> 45°	49°		
Max Load Capacitance	1 nF	_		
Line Regulation	< 2 mV/V	1.7 <i>mV /V</i>		
Load Regulation	< 50 mV/A	9 mV/A		
Power Supply Rejection at 1 MHz	30 <i>dB</i>	10 <i>dB</i>		
Power Supply Rejection at 10 MHz	20 <i>dB</i>	4 dB		
FOM	-	$2.16 * 10^{-6} (ns)$		

Design Challenges



1. Why Al-shyoukh?

Fast-transient response and stability

2. PSR

Bypass device length, low-pass filter and El-Nozahy's paper

3. Line regulation

Magical mismatch effect

4. Load regulation

Decrease the bypass current normalized change

Thank You



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For more details

